

# STPS30100ST

### Power Schottky rectifier

### Main product characteristics

I <sub>F(AV)</sub>	30 A
V <sub>RRM</sub>	100 V
T <sub>j</sub> (max)	150° C
V <sub>F</sub> (typ)	0.385 V

### **Features and Benefits**

- Avalanche rated
- Low V<sub>F</sub>
- Good trade off between leakage current and forward voltage drop
- High frequency operation
- Avalanche capability specified

### Description

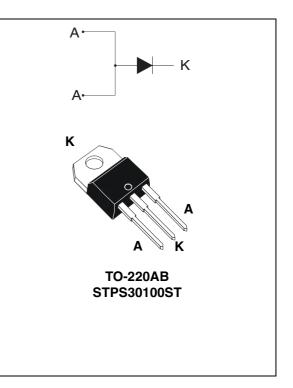
Single Schottky rectifier, suited for high frequency switch mode power supply.

Packaged in TO-220AB, this device is intended to be used in notebook and game station adaptors, providing in these applications a good efficiency at both low and high load.

Table 1.	Absolute Ratings (limiting values)

Symbol	Parame	Value	Unit	
V <sub>RRM</sub>	Repetitive peak reverse voltage	100	V	
I <sub>F(RMS)</sub>	RMS forward current	RMS forward current		
I <sub>F(AV)</sub>	Average forward current $\delta = 0.5$ $T_c = 125^{\circ} C$		30	Α
I <sub>FSM</sub>	Surge non repetitive forward current	t <sub>p</sub> = 10 ms sinusoidal	300	Α
P <sub>ARM</sub>	Repetitive peak avalanche power	$t_p = 1 \ \mu s \ T_j = 25^{\circ} C$	26400	W
T <sub>stg</sub>	Storage temperature range		-65 to + 175	°C
Ti	Maximum operating junction temperature	150	°C	

1.  $\frac{dPtot}{dTj} < \frac{1}{Rth(j-a)}$  condition to avoid thermal runaway for a diode on its own heatsink



### **Characteristics** 1

Table 2. Thermal resistance	ce
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Symbol	Parameter	Value	Unit
R <sub>th(j-c)</sub>	Junction to case	1	°C/W

Table 3.	Static electrical characteristics (	per diode)
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Symbol	Parameter	Test Con	Min.	Тур.	Max.	Unit			
		T <sub>j</sub> = 25° C	V <sub>B</sub> = V <sub>BBM</sub>			175	μA		
I <sub>B</sub> <sup>(1)</sup>	Reverse leakage current	T <sub>j</sub> = 125° C	v <sub>R</sub> = v <sub>RRM</sub>		20	50	mA		
'R`	neverse leakage current	$T_j = 25^\circ C$	V <sub>R</sub> = 70 V			60	μA		
		T <sub>j</sub> = 125° C	v <sub>R</sub> = 70 v		10	20	mA		
		$T_j = 25^\circ C$	I <sub>F</sub> = 5 A		0.475				
		T <sub>j</sub> = 125° C	F = 5 A		0.385				
		T <sub>j</sub> = 25° C		175       20     50       60       10     20       0.475					
V <sub>F</sub> <sup>(2)</sup>	Forward voltage drop	T <sub>j</sub> = 125° C	I <sub>F</sub> = 10 A		0.475		V		
VF.	Forward voltage drop	T <sub>j</sub> = 25° C	L _ 15 A		0.620	0.660	v		
		$T_j = 125^{\circ} C$	l <sub>F</sub> = 15 A	F = 15  A			0.525	175 μA   50 mA   60 μA   20 20   75 mA   75 mA   75 mA   20 0.660   25 0.565   40 0.800	
		T <sub>j</sub> = 25° C	1 - 20 4		0.740	0.800			
		$T_j = 125^\circ C$	I <sub>F</sub> = 30 A		0.605	0.655			

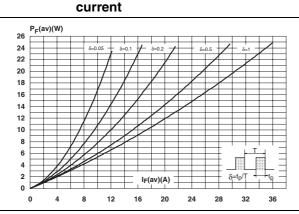
1. Pulse test:  $t_p = 5 \text{ ms}, \delta < 2\%$ 

2. Pulse test:  $t_p$  = 380 µs,  $\delta$  < 2%

To evaluate the conduction losses use the following equation: P = 0.475 x  $I_{F(AV)}$  + 0.006 x  ${I_F}^2_{(RMS)}$ 



Figure 1.



### Conduction losses versus average Figure 2. Average forward current versus ambient temperature ( $\delta = 0.5$ )

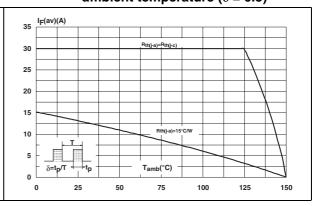


Figure 3. Normalized avalanche power derating versus pulse duration

Figure 4. Normalized avalanche power derating versus junction temperature

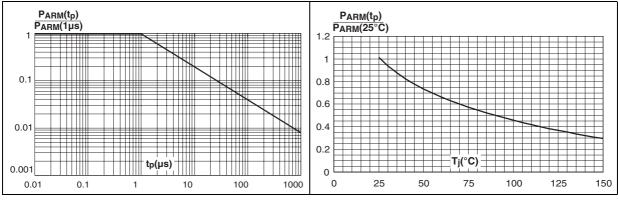
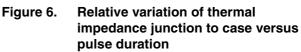
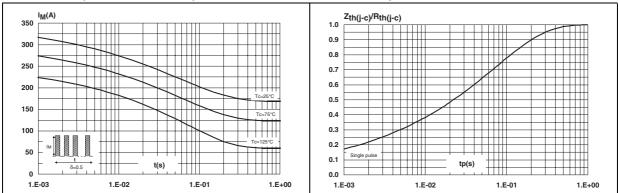


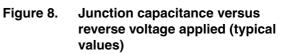
Figure 5. Non repetitive surge peak forward current versus overload duration (maximum values)

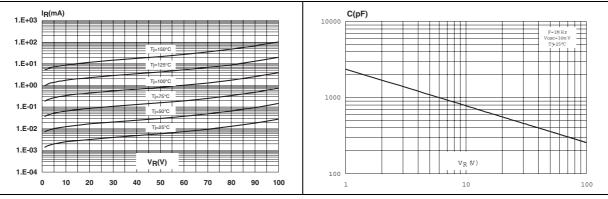




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# Figure 7. Reverse leakage current versus reverse voltage applied (typical values)





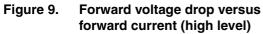
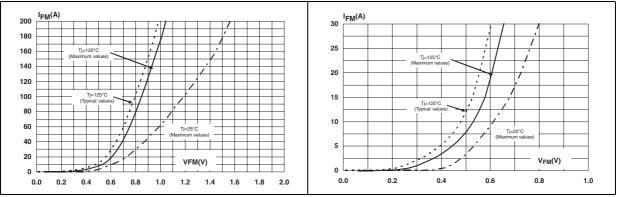


Figure 10. Forward voltage drop versus forward current (low level)



### 2 Package Information

Epoxy meets UL94,V0

Table 4. TO-220AB dimensions

					Dimer	nsions		
		Ref.	М	illimete	ers		Inches	
			Min.	Тур.	Max.	Min.	Тур.	Max.
		А	15.20		15.90	0.598		0.625
		a1		3.75			0.147	
ØI		a2	13.00		14.00	0.511		0.551
	b2, i←	В	10.00		10.40	0.393		0.409
	F	b1	0.61		0.88	0.024		0.034
A		b2	1.23		1.32	0.048		0.051
14 I3 ···.	€2	С	4.40		4.60	0.173		0.181
		c1	0.49		0.70	0.019		0.027
		c2	2.40		2.72	0.094		0.107
a2		е	2.40		2.70	0.094		0.106
	M	F	6.20		6.60	0.244		0.259
e b1	←→ <u>c1</u>	ØI	3.75		3.85	0.147		0.151
		14	15.80	16.40	16.80	0.622	0.646	0.661
		L	2.65		2.95	0.104		0.116
		12	1.14		1.70	0.044		0.066
		13	1.14		1.70	0.044		0.066
		М		2.60			0.102	

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

# **3** Ordering Information

Ordering type	Marking	Marking Package Weigh		Base qty	Delivery mode	
STPS30100ST	STPS30100ST	TO-220AB	2.23 g	50	Tube	

## 4 Revision History

Date	Revision	Changes
24-Oct-2006	1	First issue



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